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A high-energy sodium-ion capacitor enabled by a nitrogen/sulfur co-doped hollow carbon nanofiber anode and an activated carbon cathode†

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Nonaqueous Na-ion capacitors (NICs) have been recently regarded as potential sustainable power devices due to their high specific energy/power and the abundant distribution of sodium resources on the Earth. However, the power performance of current NICs is usually restricted by the kinetics imbalance between sodium deintercalation/intercalation in the anode and surface ion adsorption/desorption in the cathode. Herein, we demonstrate superior sodium-ion storage properties of nitrogen/sulfur co-doped hierarchical hollow carbon nanofibers (N/S-HCNFs) for their application as an ideal anode material for NICs. The N/S-HCNFs are fabricated through *in situ* gas sulfuration of a hollow polyaniline nanofiber precursor, which is obtained with the aid of citric acid templates. Benefiting from the positive synergistic effects of both N and S co-doping in carbon and the hierarchical hollow one-dimensional structure, the sodium-storage performance of N/S-HCNFs half-cell *versus* Na/Na⁺ exhibits a high capacity (~447 mA h g⁻¹ at 50 mA g⁻¹), excellent rate capability (~185 mA h g⁻¹ at 10 A g⁻¹), and outstanding cycling stability (no capacity decay after 3000 cycles at 5 A g⁻¹), which is among the best sodium-ion storage performances of carbonaceous Na-storage anodes. Furthermore, a dual-carbon NIC device is constructed with N/S-HCNFs as an anode and activated carbon (AC) as a cathode, and it has a large energy density of 116.4 W h kg⁻¹, a high power density of 20 kW kg⁻¹ (at 48.2 W h kg⁻¹) and a long cycle life of 3000 cycles, which is superior to most reported AC-based NICs.

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Introduction

With the increasing demand for new-generation electronics,^{1,2} such as portable electronic devices, electric vehicles, scalable grid storage, *etc.*, future energy-storage systems are required to possess both high energy and large power densities as well as excellent cycling performance.³ Li-ion batteries (LIBs) are regarded as the most popular energy-storage devices, which show obvious superiority in terms of specific energy.⁴ However, LIBs usually suffer from their low power density and poor cycling stability owing to inherently slow solid-state diffusion and agglomeration of active materials during cycling.⁵ Therefore, it is important and urgent to find a substitute battery system. Recently, sodium-ion batteries (SIBs) have been considered to be one of the most important battery devices due

to not only the abundant sodium resources on the Earth but also the similar physical and chemical properties of sodium and lithium.^{6–8} However, like LIBs, SIBs also have the drawbacks of low power performance and poor cycle life due to slow Na⁺ diffusion in bulk electrodes. Conversely, electrochemical capacitors (ECs) show high power characteristics, fast charge/discharge rate and long-term cycling performance, while their energy density is relatively low.^{9–11} Thus, designing a hybrid energy system that can integrate the merits of both batteries and ECs has become an important research hotspot in high-performance energy storage. In this regard, hybrid metal (such as Li and Na) ion capacitors are becoming more and more popular in the energy storage field.

Since the first report in 2001,¹² the research on Li-ion capacitors (LICs) has made great progress. In a LIC, activated carbon (AC) is usually applied as the cathode material, while the anode materials include Li₄Ti₅O₁₂,¹³ Nb₂O₅,¹⁴ TiO₂,¹⁵ MnO₂¹⁶ and so on. By contrast, the charge–discharge curves of many Na⁺-storage materials have no obvious charge/discharge plateau, which is a capacitor-like feature.¹⁷ This feature makes Na-ion capacitors (NICs) more suitable for high-rate energy storage. In addition, the cost of NICs will be lower compared with that of LICs. In the NIC configuration, two different storage mechanisms occur at the electrodes, where the anode provides large

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All the tests were performed at room temperature. Cyclic voltammetry (CV) and galvanostatic charge/discharge (GCD) measurements were carried out using electrochemical workstations (CHI660E, Shanghai, China). Cycling and rate performances were tested using a battery test system (Land CT2001A model, Wuhan Land Electronics Ltd). Electrochemical impedance spectra (EIS) were measured with an amplitude of 5.0 mV in the frequency range of 10^{-2} to 10^5 Hz.

The Ragone plots of the as-fabricated NIC device were obtained by calculating the energy density (E) and power density (P) from the galvanostatic discharge curves according to the equations:

$$P = V \times i \quad (1)$$

$$E = P \times t/3600 \quad (2)$$

$$V = (V_{\max} + V_{\min})/2 \quad (3)$$

where i is the current density based on the total mass of the anode and cathode ($A\ g^{-1}$), t is the discharge time (s), V_{\max} and V_{\min} correspond to voltages at the beginning and end of the discharge (V), respectively.

Result and discussion

Preparation and characterization

The fabrication process of the N/S-HCNFs involves two major steps as illustrated schematically in Fig. 1a. Firstly, the hollow polyaniline nanofibers (PNFs) were synthesized by a self-assembly method.³⁴ During the polymerization process, citric

acid molecules first spread into one-dimensional (1D) micelles to serve as a soft template. According to the molecular formula of citric acid ($\text{HOOCCH}_2\text{C}(\text{OH})(\text{COOH})\text{CH}_2\text{COOH}$), it is reasonable to think that the micelles formed by the citric acid molecules first spread into one-dimensional (1D) micelles to serve as a soft template during the polymerization process due to its hydrophobic alkyl chain and hydrophilic COOH groups. Since the aqueous ammonium persulfate is hydrophilic, the polymerization of aniline can only be performed at the water-micelle interface. After that, the aniline molecules undergo polymerization along the 1D template and further grow on the surface. After removing the template molecules, hollow nanofibers were finally obtained. In addition, since the surface of the citric acid template is not smooth, there will be additional small nanodots or nanorods on the resulting nanofibers. In the second step, the as-prepared polyaniline nanofibers were mixed with sulphur with a mass ratio of $m_{\text{polyaniline}} : m_{\text{sulphur}} = 1 : 4$, and thermally treated in a tubular furnace at $800\ ^\circ\text{C}$ under an argon atmosphere for 2 h at a heating rate of $5\ ^\circ\text{C}\ \text{min}^{-1}$ to obtain the N/S-HCNFs. For comparison, N-doped hollow carbon nanofibers (denoted as N-HCNFs) were also obtained by the same process as that of N/S-HCNFs in the absence of sulphur. Meanwhile, bulk N-doped carbon (denoted as N-n-HCNFs) was also prepared by a similar process to that of N-HCNFs without using the citric acid template. As shown in Fig. 1b, in comparison with pristine carbon, N-doped carbon has been demonstrated to display much improvement as anode material for sodium storage. Compared to nitrogen, doped sulfur atoms have larger size and smaller electronegativity, which further enlarge the interlayer distance, generate active sites, and

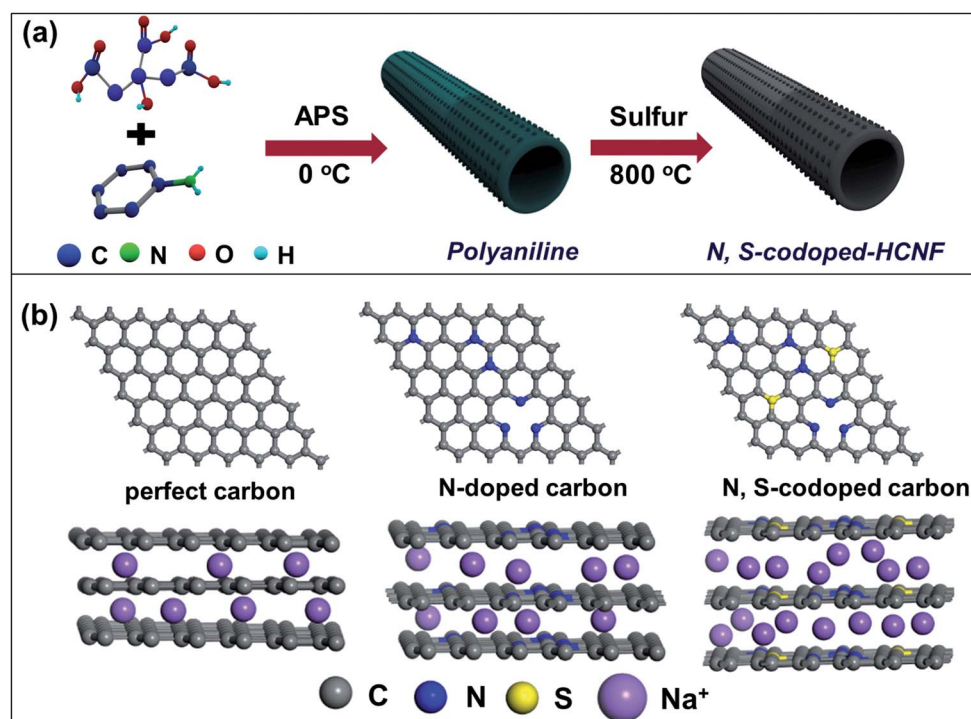


Fig. 1 (a) Schematic illustration of the synthesis of N/S-HCNFs, and (b) the sodium storage behavior of the pristine, N-doped, and N, S co-doped carbon with different geometric configurations and different interlayer distances.



significantly enhance electronic properties of carbonaceous materials.³⁵ As a result of the positive synergistic effect of binary-heteroatom doping, N/S co-doped-HCNFs will achieve high electrical conductivity and large interlayer distance, which finally provide excellent Na-storage performance.

The morphology and microstructure of the samples were investigated by SEM and TEM. Fig. 2a and b show the typical SEM images of the PNF precursor. It can be clearly observed that the PNFs show a very regular 1D structure of nanofibers, with many polyaniline nanodots uniformly dispersed on the external surface of the nanofibers. The TEM image (Fig. 2c) indicates that PNFs exhibit a hollow fiber structure several micrometers in length with an outside diameter of ~ 180 nm and an inside diameter of ~ 30 nm. Meanwhile, the walls of the polyaniline nanofibers are rough and their surface is decorated with continuous nanodots, which is in line with the results of SEM. However, in the absence of citric acid monohydrate, the as-obtained polyaniline formed bulk particle aggregates (Fig. S1a and b in the ESI†). This result demonstrates the importance of citric acid molecules as a soft template for constructing the 1D morphology.³⁶ After high-temperature sulfuration at 800 °C, the as-obtained N/S-HCNFs still retained the hierarchical hollow fiber structure with a slightly rougher surface. From the end or damaged section of the nanofibers (Fig. 2d and e), the hollow architecture can be clearly observed. Similarly, the N-HCNFs have the same microstructure as N/S-HCNFs (see Fig. S2a and b in the ESI†). The unique structure of N/S-HCNFs can offer

more electrochemically active sites for sodium ion insertion. On the other hand, it also offers sufficient contact between the active material and the electrolyte, and further shortens the transport path of ions. In addition, the high-resolution TEM image (Fig. 2h) indicates that N/S-HCNFs exhibit an amorphous structure and few-layer-stacked graphene crystallites with a large interlayer distance of 0.39 nm. This disordered carbon structure is also demonstrated by the selected-area electron diffraction (SAED) pattern (Fig. 2i).

In order to further understand the crystal phase and the pore structure of N/S-HCNFs, XRD, Raman spectroscopy and nitrogen adsorption/desorption measurements were performed. The XRD patterns of PNFs, N/S-HCNFs, N-HCNFs, and N-n-HCNFs are shown in Fig. 3a. The PNFs show broad peaks centered at $2\theta = 20.5^\circ$, 25.6° and 30.1° , which are ascribed to (011), (020) and (200) crystal planes of polyaniline with the emeraldine salt structure, respectively.³⁷ Furthermore, two broad diffraction peaks of (002) and (100) planes are observed for N/S-HCNFs, N-HCNFs, and N-n-HCNFs, which are characteristic of their disordered carbon structure. No diffraction peaks of sulfur are found in the XRD patterns of N/S-HCNFs, indicating a total carbonization of polyaniline. Based on the specific position of the (002) diffraction peak, the peaks for N/S-HCNFs and N-HCNFs are centered at 23.09° and 24.06° , respectively, indicating more lattice distortion and defects. According to Bragg's equation, the calculated interlayer spacing increased from 0.3481 to 0.3674 nm, proving that S-doping can

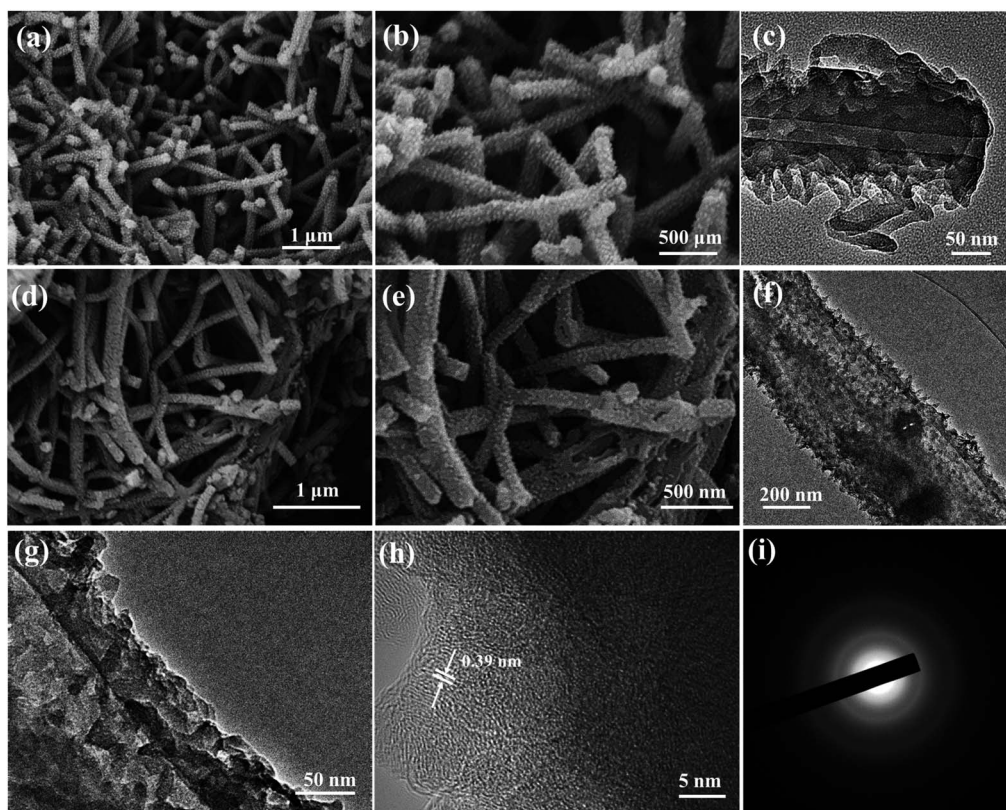


Fig. 2 SEM images of the hierarchical PNF precursor (a and b) and N/S-HCNFs (d and e). TEM images of polyaniline nanofibers (c) and N/S-HCNFs (f–h). SAED pattern (i) of the N/S-HCNFs.



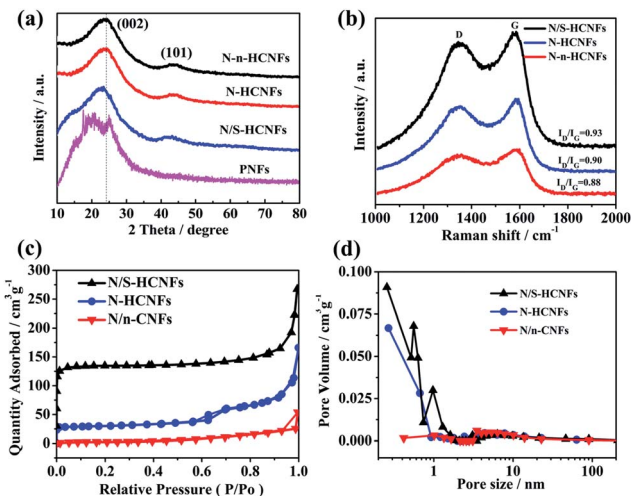


Fig. 3 XRD patterns (a), Raman spectra (b), nitrogen adsorption-desorption isotherms (c) and pore size distribution (d) of the as-synthesized N/S-HCNFs, N-HCNFs, PNFs and N-n-HCNFs.

enlarge the interlayer distance of carbon. Since sulfur has a larger covalent diameter than that of carbon, the replacement of carbon by sulfur will lead to an increase in the spacing between adjacent carbon sheets.³⁸ Raman spectra (Fig. 3b) show the characteristic peaks of typical carbon materials at $\approx 1350\text{ cm}^{-1}$ (D band) and $\approx 1590\text{ cm}^{-1}$ (G band). The N/S-HCNF sample exhibits a higher intensity ratio of D vs. G bands ($I_D/I_G = 0.93$) compared with N-HCNFs ($I_D/I_G = 0.90$) and N-n-HCNFs ($I_D/I_G = 0.89$). This can be reasonably due to the appropriate doping with S for generating more defects in the carbon material. The N_2 adsorption/desorption isotherms of the samples are shown in Fig. 3c. Comparatively, the N/S-HCNFs show a high surface area of $397.7\text{ m}^2\text{ g}^{-1}$, while the N-HCNFs and N-n-HCNFs show relatively smaller surface areas of 138.3 and $13.6\text{ m}^2\text{ g}^{-1}$, respectively. Obviously, the high surface area of N/S-HCNFs results from the 1D hollow structure and the sulfur treatment. Fig. 3d shows the pore size distributions of all samples, demonstrating the existence of abundant micropores in N/S-HCNFs. The large surface area and high pore volume of N/S-HCNFs will provide abundant and enough transport channels for fast Na^+ insertion/extraction, and ensure adequate contact between the electrolyte and the active material.

The XPS data were used to analyze the chemical bonding configuration of the N/S-HCNFs. The full survey spectra of the as-prepared N/S-HCNFs clearly indicate the presence of C, N, O, and S elements on the surface (Fig. 4a). As illustrated in Fig. 4b, the C 1s peak of N/S-HCNFs is disintegrated into four peaks at 284.7, 285.7, 287.4, and 290.5 eV, corresponding to C=C,³⁹ C-N,⁴⁰ C-S,⁴¹ and O-C=O,⁴² respectively. Moreover, the N 1s peak is decomposed into three peaks centered at 397.8,⁴³ 399.7,⁴⁴ and 400.9 eV,⁴⁵ which are consistent with pyridinic N, pyrrolic N, and quaternary N (Fig. 4c). The total N content is about 7.01% in the N/S-HCNF sample, which is lower than that (about 7.87%) of N-HCNFs (see Table S1 and Fig. S4 in the ESI[†]). It is well known that N-doping can generate some extrinsic defects and increase reactivity and electron conductivity.⁴⁶ Fig. 4d shows the high-

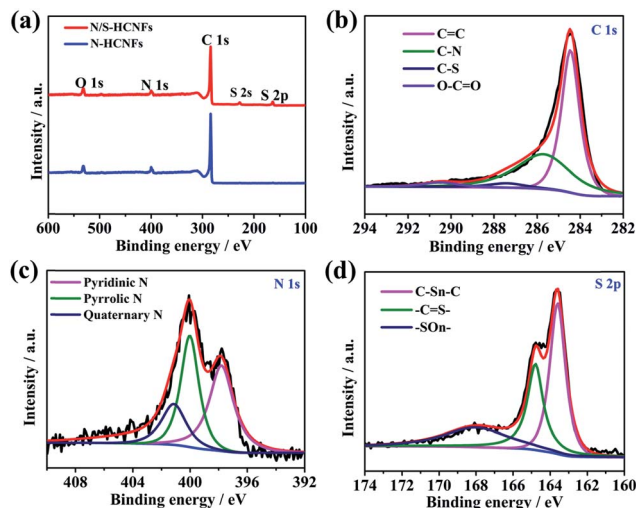


Fig. 4 XPS survey spectra of N-HCNFs and N/S-HCNFs (a); C 1s (b), N 1s (c), and S 2p (d) spectra of N/S-HCNFs.

resolution S 2p spectrum of N/S-HCNFs. It can be found that the sulfur in N/S-HCNFs exists in three different chemical states with a content of 3.15% (Table S1, ESI[†]), which are attributed to C-Sn-C ($n = 1$ or 2) bonds, conjugated $-\text{C}=\text{S}-$ bonds, and oxidized ($-\text{SON}-$) bonds.⁴⁷ This result confirms that sulfur has been successfully embedded into the hollow carbon nanofibers.³⁴ Meanwhile, compared with N-HCNFs, N/S-HCNFs will generate more external defects and active sites. Such topological defects as well as active sites can adsorb more sodium ions, thereby improving sodium storage capacities.

Electrochemical performance

Sodium-ion half-cell performance

To further describe the electrochemical behavior of N/S-HCNFs, CV and GCD tests were performed. In order to demonstrate the advantage of N/S-HCNFs, the Na-storage performance of N-HCNFs and N-n-HCNFs is also tested under the same mass loading. Fig. 5a-c reveal the first three CV curves of N/S-HCNFs-800, N-HCNFs and N-n-HCNFs at a scan rate of 0.1 mV s^{-1} between 0.01 and 3.0 V (vs. Na/Na⁺). During the first negative scan, the peaks were present at 0.8 and 1.2 V for all samples, which were attributed to the decomposition of the electrolyte, the irreversible reaction of Na⁺ ions with the surface functional groups and the formation of a solid electrolyte interface (SEI) film. After the initial cycle, these peaks could disappear.⁴⁸ The peaks in the potential range of 0.01 to 0.1 V can be ascribed to Na⁺ insertion/extraction in the carbon materials. However, the CV curves of N/S-HCNFs-800 are quite different from those of N-HCNFs and N-n-HCNFs. There is an additional reduction peak at 1.1 V from the beginning of the 2nd cycle of N/S-HCNFs, indicating a reduction reaction between Na and S, and there is a corresponding anodic peak at 1.85 V in the reverse process.^{49,50} This phenomenon is in agreement with that of the previously reported S-doped carbon in Na-storage and Na-S batteries.⁵¹ In the subsequent cycles, the CV curves of the N/S-



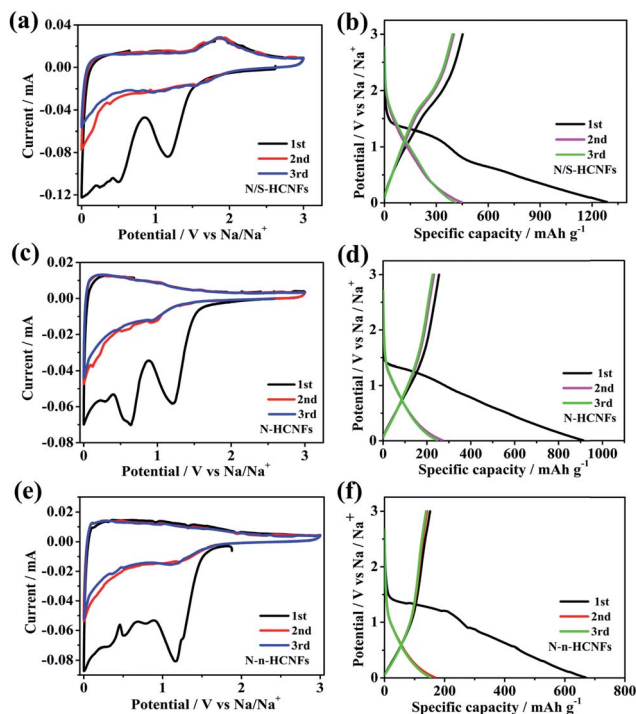


Fig. 5 CV curves of N/S-HCNFs (a), N-HCNFs (b) and N-n-HCNFs (c) at a scan rate of 0.1 mV s^{-1} ; the first three GCD profiles of N/S-HCNFs (d), N-HCNFs (e), and N-n-HCNFs (f) at 0.05 A g^{-1} .

HCNFs-800 electrode almost overlapped, which shows excellent reversibility of the N/S-HCNF electrodes. Fig. 5d–f show the first three GCD profiles of the three samples at a current density of 0.05 A g^{-1} . During the first discharge cycle, the GCD profiles of the N-HCNFs and N-n-HCNFs are typical of hard carbon. In contrast, a discharge plateau at $\sim 1 \text{ V}$ is clearly seen for the N/S-HCNFs-800. As shown in Fig. 5d, an obvious sloping platform located at $\sim 1.5 \text{ V}$ can be observed in the charge curves, which indicates that the partial capacity for N/S-HCNFs is contributed by faradaic reactions of Na^+ with the covalently bonded S. The first discharge (charge) capacities of N/S-HCNFs-800, N-HCNFs, and N-n-HCNFs anodes were 1286 (452), 912 (255), and 669 (151) mA h g^{-1} , respectively, corresponding to an initial coulombic efficiency (ICE) of 35.1% , 27.9% , and 22.5% , respectively. The low ICE is caused by the formation of the SEI layer and the irreversible side reactions between Na^+ and surface functional groups. After several cycles, the coulombic efficiency could be completely increased and could approach 100% .

Fig. 6a shows the rate performance of N/S-HCNFs-800, N-HCNFs and N-n-HCNFs, tested at different current densities from 0.05 to 10 A g^{-1} for 5 cycles. Compared with the other two samples, N/S-HCNFs-800 show an excellent rate performance, with reversible capacities of 446.9 , 349.2 , 312.6 , 275.8 , 237.8 , 215.6 , 198.3 , and $185.1 \text{ mA h g}^{-1}$ obtained at 0.05 , 0.1 , 0.2 , 0.5 , 1 , 2 , 5 and 10 A g^{-1} with 5 cycles at each step. After the high-rate measurement, a high specific capacity of $348.3 \text{ mA h g}^{-1}$ at 0.1 A g^{-1} could still be recovered for the N/S-HCNFs-800 electrode. For N-HCNFs without S doping, when the current density

increased to 10 A g^{-1} , the N-HCNF electrode delivers a low specific capacity of about 95.7 mA h g^{-1} . Comparatively, the capacity of the N-n-HCNF electrode is only 58.7 mA h g^{-1} at 10 A g^{-1} . The GCD curves at different current densities further confirm these rate results (Fig. 6c and S5 in the ESI†). Thus, the N/S-HCNF electrode exhibits much better rate performance than other control samples. Further, compared with the already reported carbon materials in the literature^{52–54} (Table S2, ESI†), the N/S-HCNFs have an excellent sodium-storage performance.

Generally, the N and S contents and the graphitization degree in N/S-HCNFs will be significantly changed with annealing temperature (see Table S1, ESI†), which can further affect the electrochemical performance. Here we also compare the sodium-storage performance of the N/S-HCNF samples at different annealing temperatures (700 , 800 , and $900 \text{ }^\circ\text{C}$). Fig. 6b presents the specific capacities of N/S-HCNFs-700, N/S-HCNFs-800 and N/S-HCNFs-900 at different current densities. Obviously, the N/S-HCNFs-800 electrode showed relatively higher capacities ($185.1 \text{ mA h g}^{-1}$ at 10 A g^{-1}) than those of N/S-HCNFs-700 ($147.9 \text{ mA h g}^{-1}$ at 10 A g^{-1}) and N/S-HCNFs-900 ($111.6 \text{ mA h g}^{-1}$ at 10 A g^{-1}). In addition, N/S-HCNFs-700 and N/S-HCNFs-900 are superior to N-HCNFs without S doping. These results indicate that the optimal temperature for the formation of N/S-HCNFs is $800 \text{ }^\circ\text{C}$.

Fig. 6d shows the cycling performance of the N/S-HCNFs-800, N-HCNF and N-n-HCNF electrodes at a current density of 0.5 A g^{-1} . After 800 cycles, the N/S-HCNF electrode still exhibits a high specific reversible capacity of $224.7 \text{ mA h g}^{-1}$. Moreover, N-HCNFs and N-n-HCNFs retain reversible capacities of 182.5 and $104.6 \text{ mA h g}^{-1}$, respectively. Apparently, N/S-HCNFs-800 has a much higher reversible capacity than N-HCNFs and N-n-HCNFs, due to the synergy effects of the hollow nanofiber structure and N/S co-doping. The GCD curves at the 1st, 300th, and 800th cycle at 0.5 A g^{-1} further demonstrate these cycling results (ESI†). To further clarify the significant Na-storage performance at relatively high current densities, all samples were evaluated at 5.0 A g^{-1} for long cycling. As shown in Fig. 6e, the N/S-HCNFs-800 shows outstanding cycling performance, and the capacity is maintained at $202.3 \text{ mA h g}^{-1}$ even after 3000 cycles. The overall capacity decay can be neglected. The coulombic efficiency approaches 100% , indicating stable reversibility. The N-HCNF and N-n-HCNF electrodes also exhibit good cycling ability, but their specific capacities after 3000 cycles are relatively low in comparison to that of N/S-HCNFs. In Fig. 6e, the capacity increase for N-HCNFs may be caused by the activation and the formation of a stable SEI film.

In order to evaluate the electrochemical kinetics of N/S-HCNFs, the electrode was further explored by CV using different scan rates ranging from 0.5 to 10 mV s^{-1} , and the capacitive contribution to the charge storage was evaluated. The original shape of the CV curves of the N/S-HCNF electrode was well maintained with increasing the scan rate to 10 mV s^{-1} (Fig. 7a). This result also reveals the fast diffusion of Na ions into the N/S-HCNFs. The degree of the capacitive effect can be qualitatively calculated based on the relationship between the measured current (i) and the scan rate (ν) from the CV curves: $i = a\nu^b$, where a and b are adjustable parameters.⁵⁵ The b value



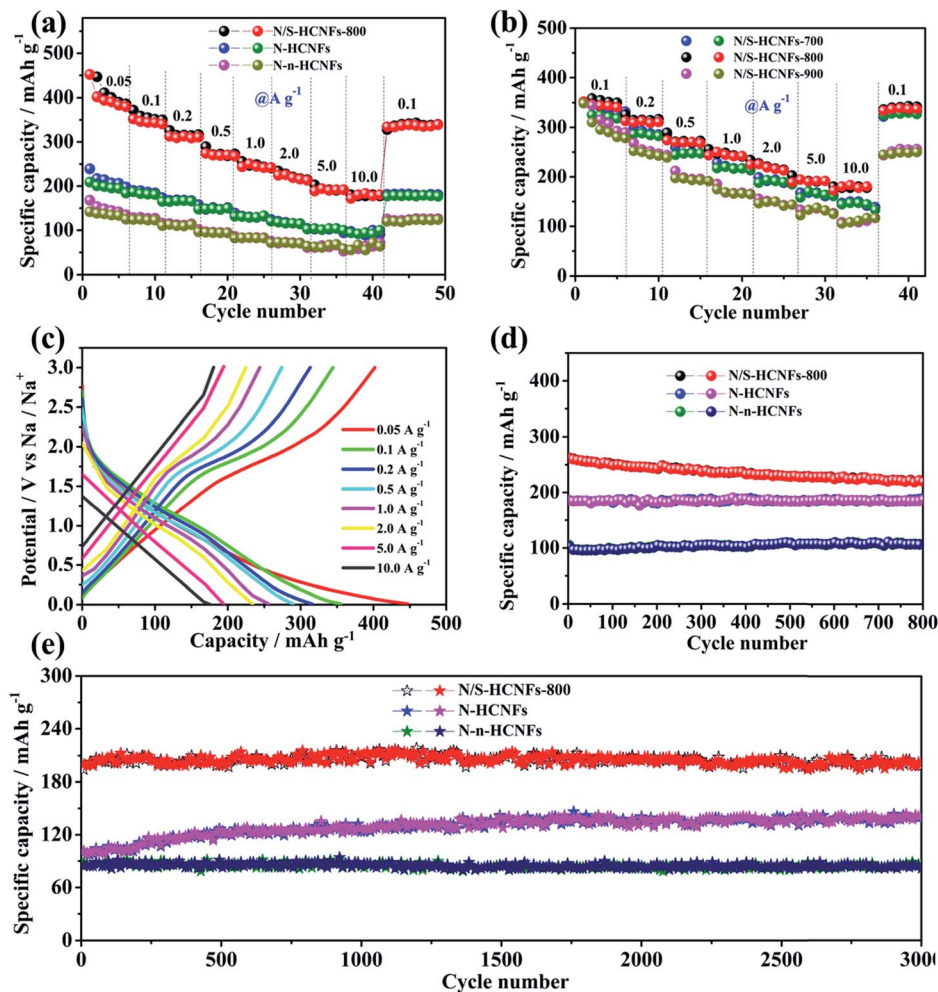


Fig. 6 Electrochemical performance of the as-synthesized N/S-HCNFs, N-HCNFs, and N-n-HCNFs. Rate performance (a and b). GCD curves at different current densities (c). Cycling performance at a current density of 0.5 A g⁻¹ (d) and 5.0 A g⁻¹ (e).

can be obtained from the slope of the $\log i$ vs. $\log \nu$ plot (Fig. S7 in the ESI[†]). Fig. 7b shows the separation of the diffusion controlled and the capacitive contribution of the N/S-HCNF electrode. The diffusion-type contribution reduced gradually with increasing scan rate (Fig. 7c), but the capacitive-type contribution was enhanced. At a scan rate of 10 mV s⁻¹, 88% of the total capacity is identified as the capacitive contribution for the N/S-HCNF electrode, which is higher than 83% for the N-HCNF sample (Fig. 7d–f). This high capacitive contribution may be ascribed to the S-doping-induced larger interlayer distance, lower Na⁺ diffusion barrier and higher electronic conductivity facilitating the Na⁺-ion insertion/extraction. This result indicates that the N/S-HCNFs are beneficial to fast kinetics of Na-ion storage.

In order to further indicate the structural merits of N/S-HCNFs, the electrochemical impedance spectroscopy (EIS) of N/S-HCNFs-800, N-HCNFs and N-n-HCNFs is shown in Fig. S8 in the ESI[†]. The three EIS curves have a common feature, in which the intercept at the high-frequency end is equal to the electrolyte resistance (R_s), the semicircle size at the medium-frequency response is the charge-transfer resistance, and the

low-frequency line is indicative of the Warburg impedance related to Na⁺ diffusion. Apparently, the diameter of the semi-circle for N/S-HCNFs in the high-frequency region is significantly smaller than that for N-HCNFs and N-n-HCNFs. Specifically, the values of the charge-transfer resistance for N/S-HCNFs, N-HCNFs and N-n-HCNFs are about 125, 203 and 248 Ω , respectively, and the SEI film resistance is about 5.88, 12.68, 23.53 Ω , respectively. This result indicates that the N/S-HCNF electrode possesses lower charge-transfer impedance and SEI film resistance because of S-doping, which can result in rapid electron transport during the electrochemical sodium insertion/extraction reactions.

The excellent Na-storage properties of the N/S-HCNF electrode can be reasonably attributed to: (1) its hierarchical 1D hollow nanofiber structure, which reduces the mass-transfer resistance and provides sufficient active sites. (2) N, S-codoping in carbon, which results in the lowest Na⁺ adsorption energy compared to that of the pristine and N-doped carbon (see Fig. 1b), as previously confirmed by first-principles calculations.^{56,57} This indicates that the adsorption of Na⁺ onto the N/S-HCNFs is thermodynamically spontaneous.



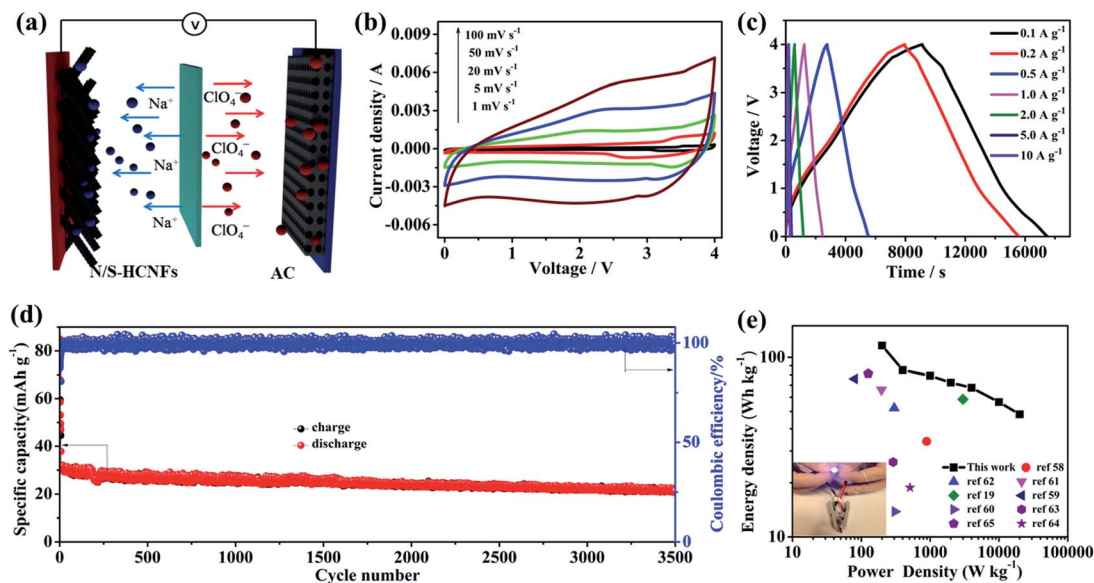


Fig. 8 (a) Schematic representation of the NIC device made of the as-prepared N/S-HCNFs as the anode and commercial AC as the cathode. (b) CV curves at various scan rates from 1 to 100 mV s^{-1} . (c) GCD curves of the as-assembled NIC at different current densities based on the total mass of N/S-HCNFs and AC. (d) Cycling performance of the AC//N/S-HCNF NIC between 0 and 4.0 V at a current density of 2 A g^{-1} . (e) The Ragone plot (energy density vs. power density) of the present AC//N/S-HCNF NIC and comparison with the results of other reports, and lighting a blue LED (inset) using the AC//N/S-HCNF NIC.

density and power density are calculated according to the galvanostatic discharge curves. As expected, our NIC could deliver a high energy density of $116.4 \text{ W h kg}^{-1}$ at a power density of 200 W kg^{-1} . Even at a high power density of 20 kW kg^{-1} , the NIC can still achieve 48.2 W h kg^{-1} . It should be noted that the power density of 20 kW kg^{-1} (at 48.2 W h kg^{-1}) corresponds to a full charge–discharge within 38 s, similar to capacitor features. In comparison, our NIC also exhibits better energy-storage performance than other AC-based NICs reported in ref. 19 and 58–65 (Table S3, ESI†). In addition, a light-emitting diode (LED) panel can be successfully powered by a single AC//N/S-HCNF NIC device (inset of Fig. 8e). The outstanding electrochemical performance of our dual-carbon NIC device fabricated here by using N/S-HCNFs as the anode and AC as the cathode can be attributed to the following aspects: (1) the N/S-HCNF anode possesses an interlayer spacing due to N/S co-doping, which promotes the fast diffusion of sufficient Na^+ ions. (2) The large surface area and high pore volume as well as the 1D hollow fiber structure of N/S-HCNFs can greatly increase the transfer of ions and the contact of the electrolyte. (3) The dual-carbon configuration in the NIC may be beneficial for kinetics matching and structural stability, which lead to the improvement of electrochemical performance of the hybrid device.

Conclusions

In summary, N/S co-doped hollow carbon nanofibers have been synthesized successfully *via* a facile and controllable strategy, and their superior sodium-storage performance as an anode for NICs has been presented. N/S co-doping in carbon and the

unique hierarchical hollow 1D fiber structure can lead to major capacity contribution. More importantly, N/S dual doping greatly decreases the mismatch of electrode kinetics between the cathode and anode of NICs, resulting in both high energy density and high power density. Ultimately, a high-performance dual-carbon NIC (AC//N/S-HCNFs) has been fabricated, which presents a high energy density ($116.4 \text{ W h kg}^{-1}$ at 200 W kg^{-1}), a high power density (20 kW kg^{-1} at 48.2 W h kg^{-1}), and a reasonably long cycling life (81% capacitance retention after 3000 cycles).

Conflicts of interest

There are no conflicts to declare.

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